



**SMI**

**0981-HK**

2016 8

[http://www.smics.com/download/ir\\_presentation.pdf](http://www.smics.com/download/ir_presentation.pdf)

( 1995 )

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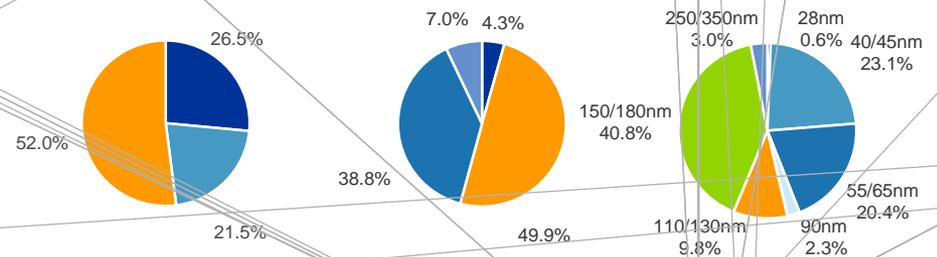




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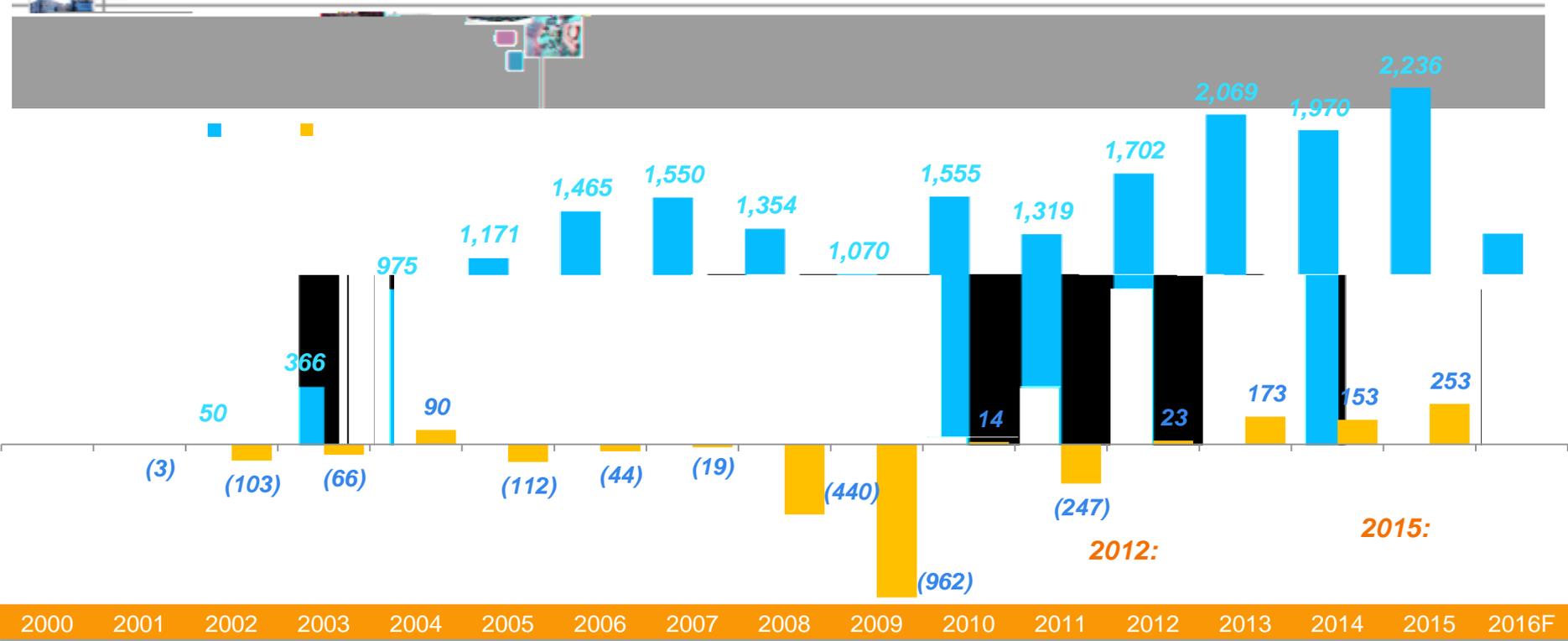
	18.25%
	17.54%
	64.21%



NASDAQ OMX, 2016 7 20

2016 : 2015 , 3 , 2







2015  
2009-2015

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### William Tudor Brown

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Cadence Design  
Systems, Inc.

, 2008 2012

(NEA)

2011 2013 ,

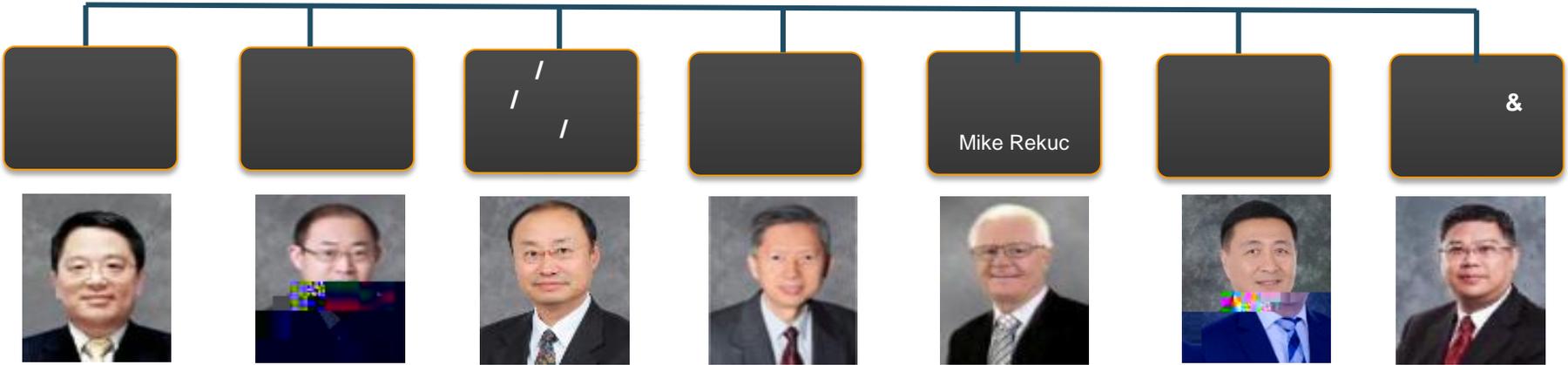




- 2009 2015:
- 2008 2009:
- 2002 2008:



- 2009 2011: NEC
- 2007 2009: Silterra Malaysia
- 2005 2006:
- 2001 2005:
- 1996 2001:
- 1984 1996: AT&T

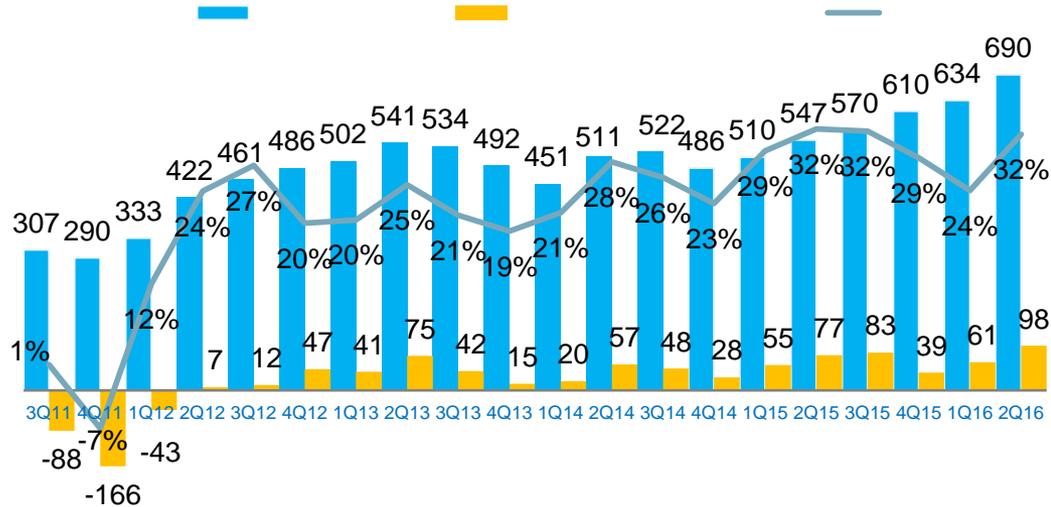




# 2016 2

- : 6 9 ,
- : 2 1 8 , 17
- : 31.6%
- : 1 1 5 ,
- : \$16.7%
- : 9 8 ,
- : 19
- : 52.0%,
- : 97.9%

## 2016 2

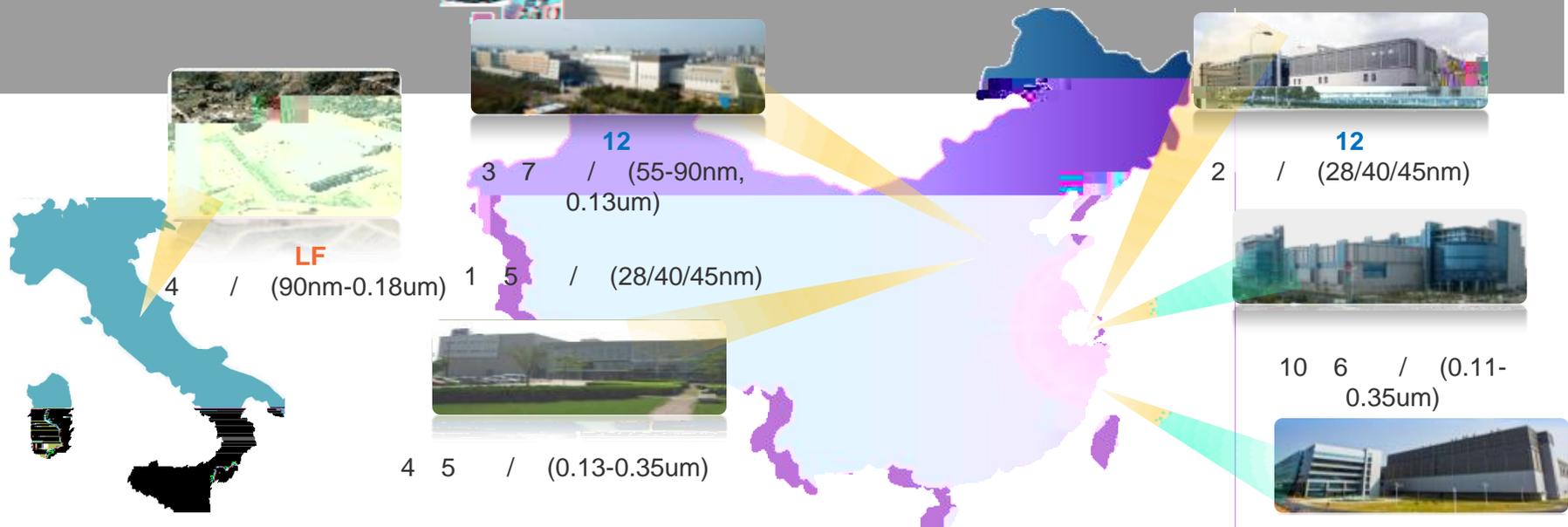


## 2016 3

	8% 11%
	7 4 5 7 6 6
	28% to 30%
(1)	1 4 1 4 5
(2)	4 6



# IC



	2	2016	
45nm	20K	20K	~20K
55-90nm, 0.13um	37K	45K	~50K
45nm	15K	18K	~35K
0.11-0.35um	106K	-	~106K
0.13-0.35um	45K	-	~45K
0.15-0.35um	26K	31K	~50K
90nm-0.18um	40K	-	~50K





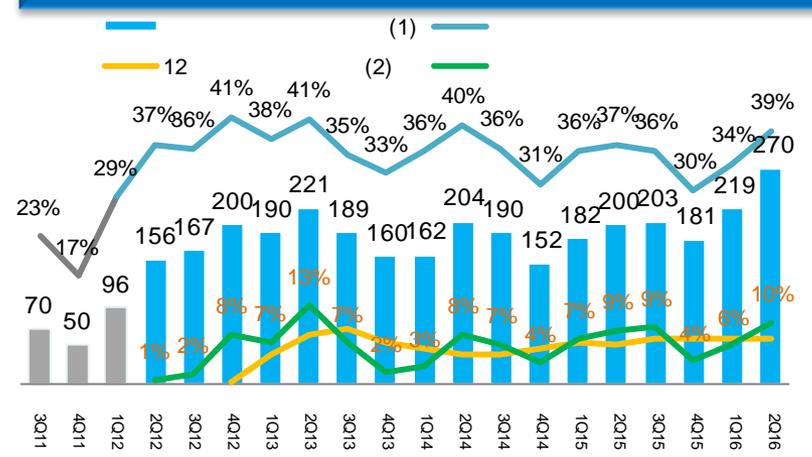
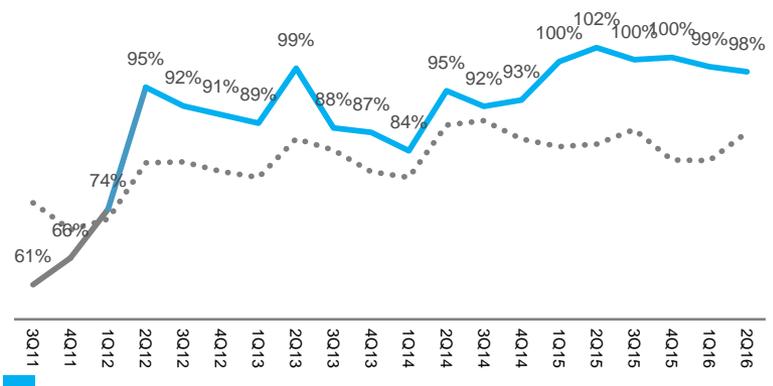
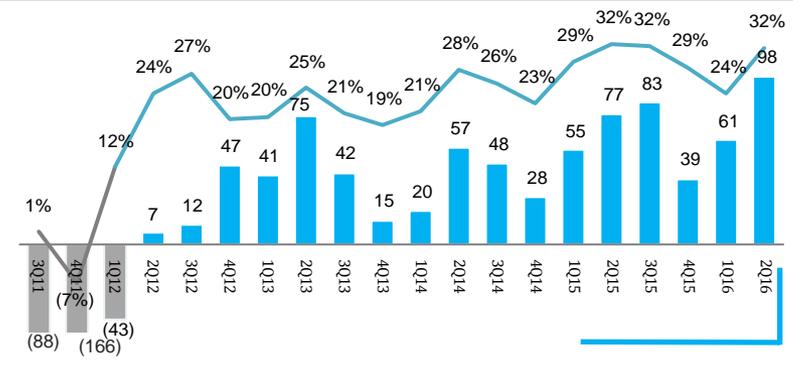
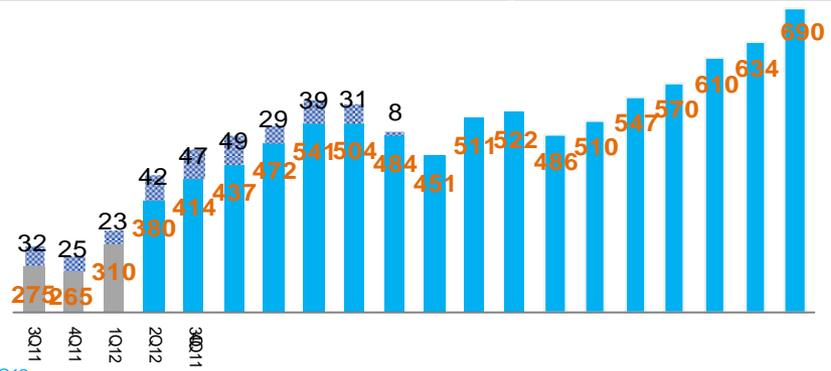
□ 简介

□ **中芯业绩**

□ 中国半导体行业机遇

□ 获利成长战略

□ 总结

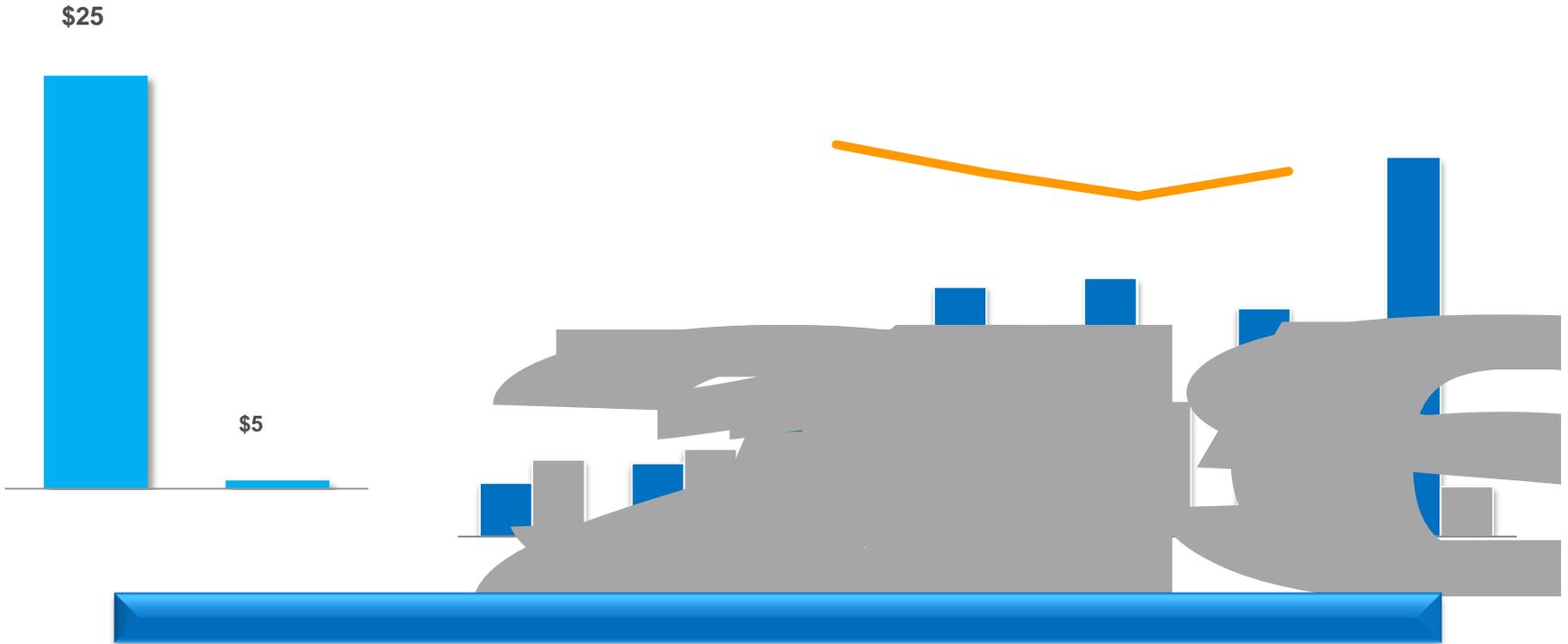


\* : 2013  
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2016

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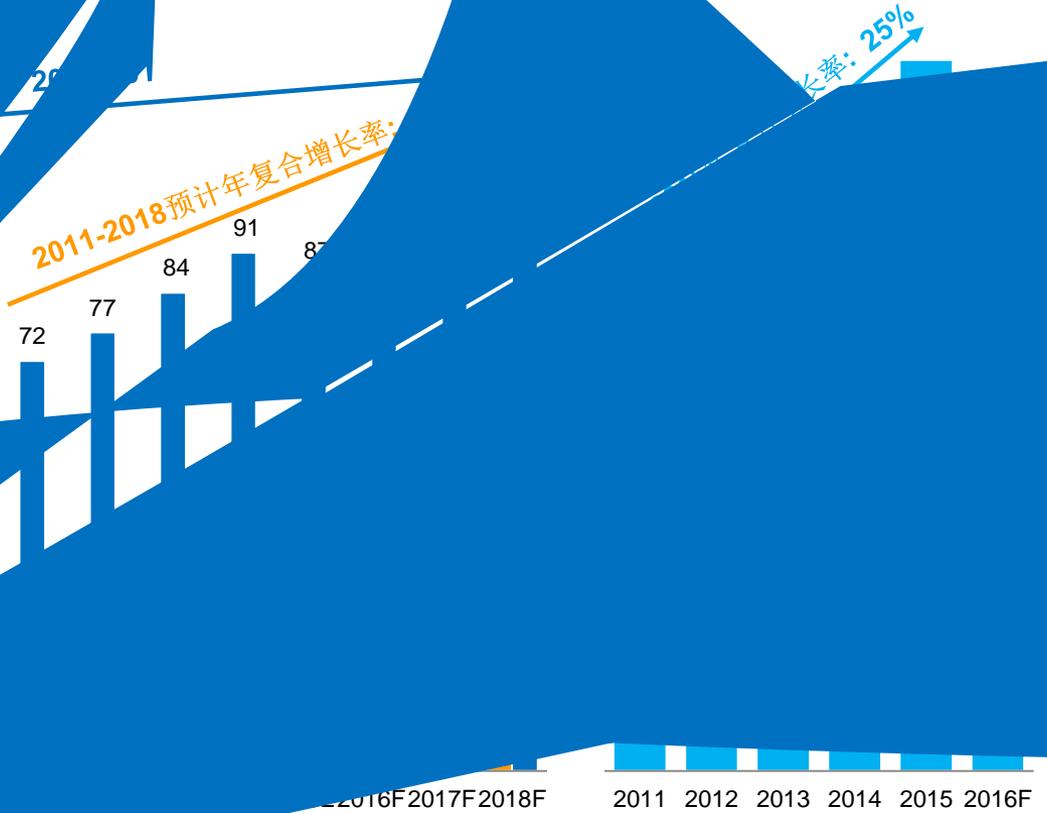
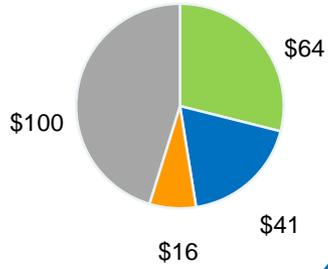


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- 简介
  - 中芯业绩
  - **中国半导体行业机遇**
  - 获利成长战略
  - 总结

# IC

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39%



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35%

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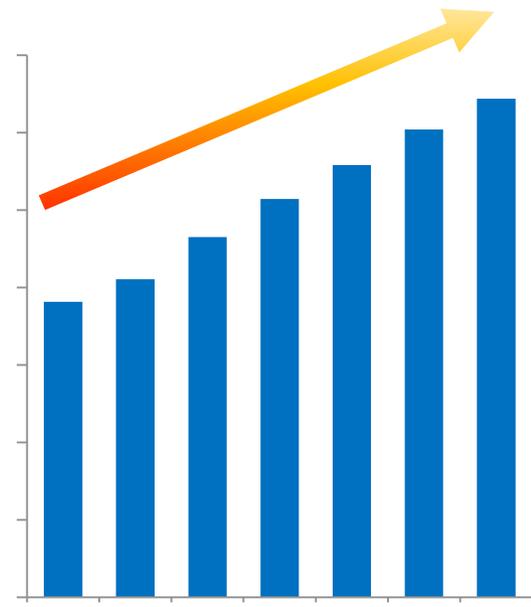
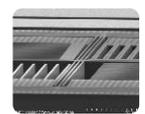
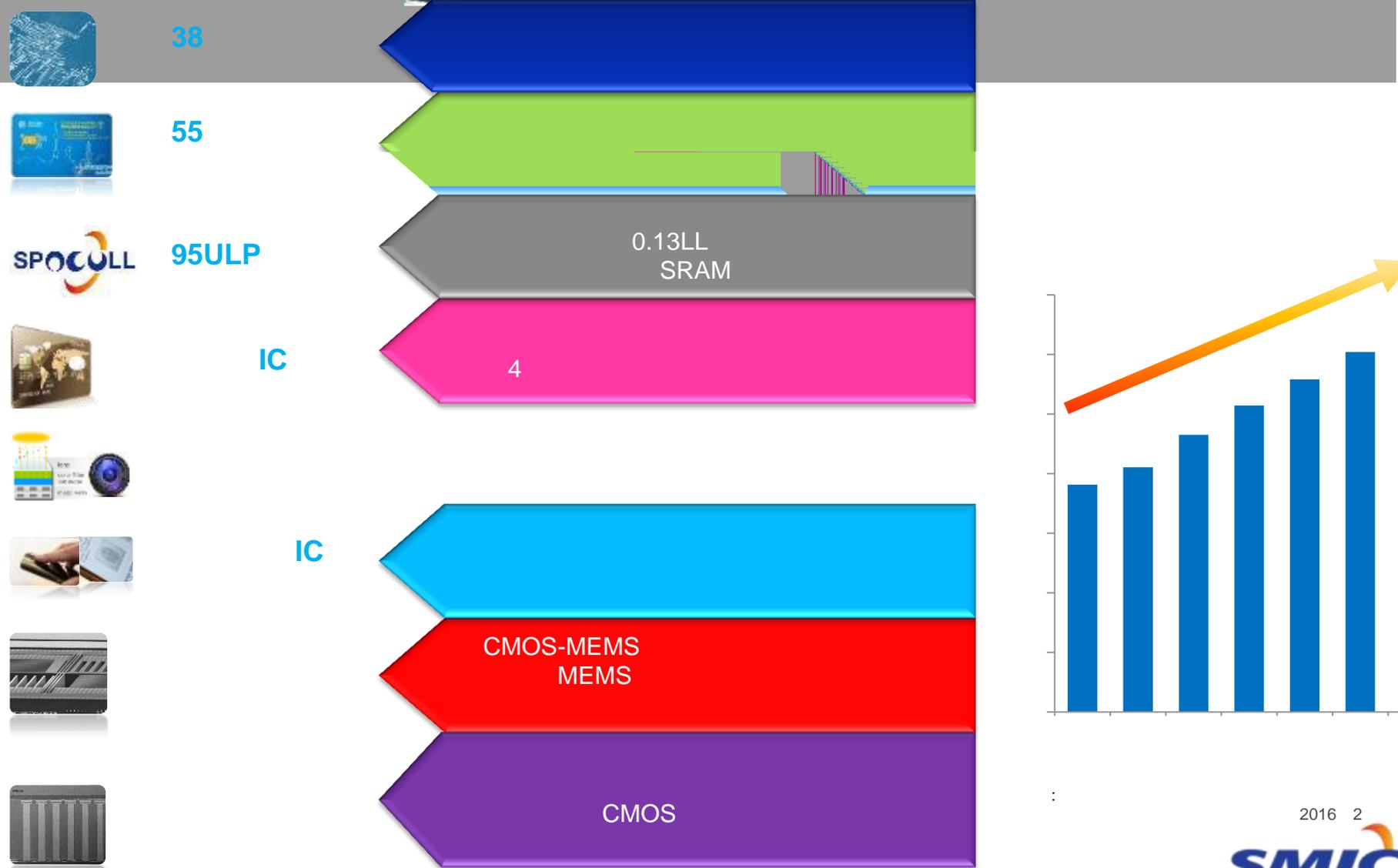




- 简介
- 中芯业绩
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- **获利成长战略**
- 总结







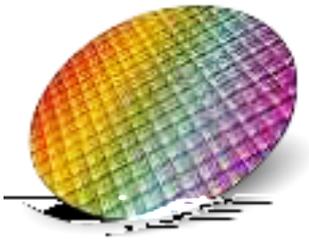
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2016 2





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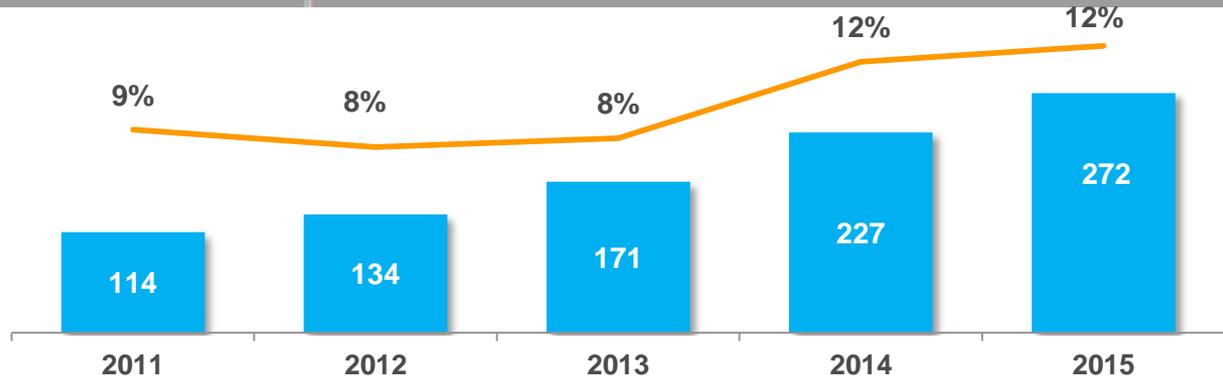
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- SPOCULL --- SMIC POly Contact for Ultra Low Leakage

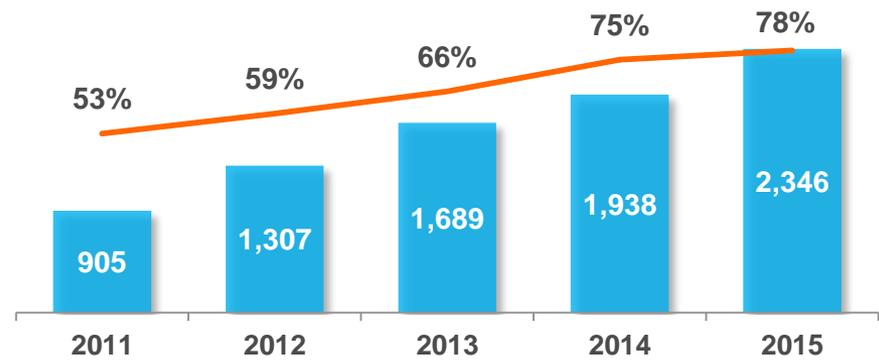
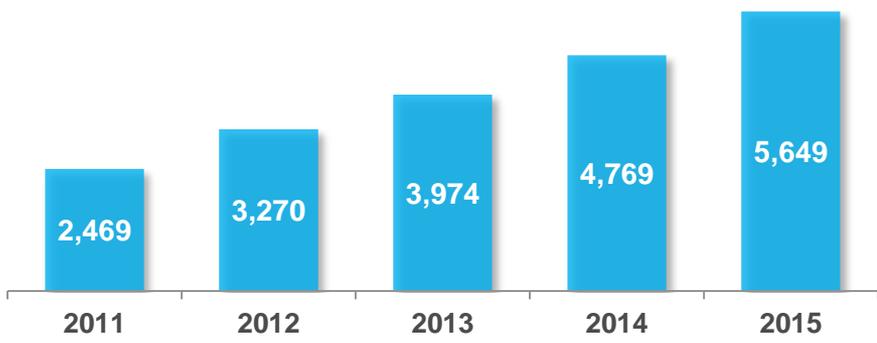




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- 简介
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- 中国半导体行业机遇
- 获利成长战略
- **总结**

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2016  
2016 25%

2016-2019 20%

28nm/40nm/55nm





: [ir@smics.com](mailto:ir@smics.com)

